

	<h2>SI2319CDS-T1-GE3</h2>
	<p>Hersteller-Teilenummer: SI2319CDS-T1-GE3</p> <p>Hersteller / Marke: Vishay / Siliconix</p> <p>Teil der Beschreibung: MOSFET P-CH 40V 4.4A SOT-23</p> <p>Datenblätter:  SI2319CDS-T1-GE3.pdf</p> <p>RoHs Status: Bleifrei / RoHS-konform</p> <p>Lagerzustand: New original, 113995 pcs Stock Available.</p> <p>Liefern von: Hong Kong</p> <p>Versandweg: DHL/Fedex/TNT/UPS/EMS</p>
	
<p>Image may be representation. See specs for product details.</p>	

Spezifikationen

Teilenummer	SI2319CDS-T1-GE3
Hersteller	Vishay / Siliconix
Beschreibung	MOSFET P-CH 40V 4.4A SOT-23
Kategorie	Diskrete Halbleiterprodukte > Transistoren-FETs,
Teilstatus	113995 pcs Stock
Serie	TrenchFET®
Technologie	MOSFET (Metal Oxide)
Betriebstemperatur	-55°C ~ 150°C (TJ)
Befestigungsart	Surface Mount
Verpackung / Gehäuse	TO-236-3, SC-59, SOT-23-3
Supplier Device-Gehäuse	SOT-23-3 (TO-236)
Verlustleistung (max)	1.25W (Ta), 2.5W (Tc)
Typ FET	P-Channel
FET-Merkmal	-
Drain-Source-Spannung (Vdss)	40V
Strom - Ununterbrochener Abfluss (Id) bei 25 °C	4.4A (Tc)
Rds On (Max) @ Id, Vgs	77 mOhm @ 3.1A, 10V
VGS (th) (Max) @ Id	2.5V @ 250µA
Gate Charge (Qg) (Max) @ Vgs	21nC @ 10V
Eingabekapazität (Ciss) (Max) @ Vds	595pF @ 20V
Antriebsspannung (Max Rds On, Min Rds On)	4.5V, 10V
Vgs (Max)	±20V
Verpackung	Tape & Reel (TR)











































SI2319CDS-T1-GE3 ist neu im Original, Suche SI2319CDS-T1-GE3 Datenblätter, PDF, Inventar bei Y-IC.com Online, Bestellen Sie SI2319CDS-T1-GE3 Vishay / Siliconix mit Garantie und Vertrauen. Anfrage SI2319CDS-T1-GE3: Info@Y-IC.com

Sie können auch interessiert sein:

 <p>SI2319DDS-T1-GE3 Electro-Films (EFI) / Vishay MOSFET P-CHAN 40V</p>	 <p>SI2318DS-T1-E3 VISHAY VISHAY SOT-23</p>	 <p>SI2319CDS-T1-E3 VISHAY SI2319CDS-T1-E3 VISHAY</p>	 <p>SI2319ADS-T1-GE3 V SI2319ADS-T1-GE3 V</p>
 <p>SI2319CDS-T1-GE3 Electro-Films (EFI) / Vishay MOSFET P-CH 40V 4.4A SOT-23</p>	 <p>SI2318DS-T1-GE3 Electro-Films (EFI) / Vishay MOSFET N-CH 40V 3A SOT-23</p>	 <p>SI2319DS-T1-E3 Electro-Films (EFI) / Vishay MOSFET P-CH 40V 2.3A SOT23-3</p>	 <p>SI2319DS 89K SI2319DS 89K</p>

heiße Teile

Mehr

 SI2316BDS-T1-E3	 SI2316BDS-T1-GE3	 SI2316BDS-T1-GE3	 SI2316DS	 SI2316DS-T1-E3
 SI2316DS-T1-E3	 SI2316DS-T1-GE3	 SI2316DS-T1-GE3	 SI2317DS	 SI2317DS-T1-E3
 SI2318ADS-T1-GE3	 SI2318BDS-T1-E3	 SI2318BDS-T1-GE3	 SI2318CDS-T1-E3	 SI2318CDS-T1-GE3
 SI2318CDS-T1-GE3	 SI2318DS	 SI2318DS-T1-E3	 SI2318DS-T1-E3	 SI2318DS-T1-GE3
 SI2318DS-T1-GE3	 SI2319ADS-T1-GE3	 SI2319C95TF	 SI2319CDS-T1-E3	 SI2319CDS-T1-GE3
 SI2319DDS-T1-GE3	 SI2319DS	 SI2319DS-T1-E3	 SI2319DS-T1-E3	 SI2319DS-T1-GE3
 SI2319DS-T1-GE3	 SI2320DS	 SI2320DS-T1-E3	 SI2320DS-T1-GE3	 SI2321DS-T1-E3
 SI2321DS-T1-E3	 SI2321DS-T1-GE3	 SI2321DS-T1-GE3	 SI2323CDS-T1	 SI2323CDS-T1-E3
 SI2323CDS-T1-GE3	 SI2323CDS-T1-GE3	 SI2323DDS-T1-E3	 SI2323DDS-T1-GE3	 SI2323DDS-T1-GE3
 SI2323DS	 SI2323DS-T1-E3	 SI2323DS-T1-E3	 SI2323DS-T1-GE3	 SI2323DS-T1-GE3

Contact us: Info@Y-IC.com

HINZUFÜGEN: Einheit A5-B5 Nr.509, 5 / F Sing Win Fabrikgebäude, 15-17 Shing Yip St, Kwun Tong, Kowloon, HongKong.

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